

TN2510N8-G

TN2510N8-G Information

www.telsener.com	Part Number	TN2510N8-G	
	Manufacturer	Microchip Technology	
	Category	Discrete Semiconductor Products Transistors - FETs, MOSFETs - Single	i
	Description	MOSFET N-CH 100V 730MA SOT89-3	
	Package	TO-243AA	i
		For the pricing/inventory/lead time, please contact us	
For Reference Only		Website: https://www.heisener.com E-mail: salesdept@heisener.com	



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Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



TN2510N8-G Specifications

Manufacturer Part Number	TN2510N8-G
Manufacturer	Microchip Technology
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	TO-243AA
Series	
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	100V
Current - Continuous Drain (Id) @ 25°C	730mA (Tj)
Drive Voltage (Max Rds On, Min Rds On)	3V, 10V
Vgs(th) (Max) @ Id	2V @ 1mA
Gate Charge (Qg) (Max) @ Vgs	-
Input Capacitance (Ciss) (Max) @ Vds	125pF @ 25V
Vgs (Max)	$\pm 20 V$
FET Feature	-
Power Dissipation (Max)	1.6W (Ta)
Rds On (Max) @ Id, Vgs	1.5 Ohm @ 750mA, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	TO-243AA (SOT-89)
Package / Case	TO-243AA
	Report errors?

TN2510N8-G Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE GUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

TN2510N8-G Payment Methods Image: I

If you have any question about TN2510N8-G, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com